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# **Typical Applications**

The HMC649ALP6E is ideal for:

- EW Receivers
- Weather & Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

# **Functional Diagram**



# HMC649ALP6E

# GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz

### Features

Low RMS Phase Error: 4° Low Insertion Loss: 8 dB High Linearity: +40 dBm Positive Control Logic 360° Coverage, LSB = 5.625° 28 Lead QFN Leadless SMT Package: 36mm<sup>2</sup>

# **General Description**

The HMC649ALP6E is a 6-bit digital phase shifter which is rated from 3 to 6 GHz, providing 360 degrees of phase coverage, with a LSB of 5.625 degrees. The HMC649ALP6E features very low RMS phase error of 4 degrees and extremely low insertion loss variation of  $\pm 0.5$  dB across all phase states. This high accuracy phase shifter is controlled with positive control logic of 0/+5V The HMC649ALP6E is housed in a compact 6x6 mm plastic leadless SMT package and is internally matched to 50 Ohms with no external components.

### Electrical Specifications $T_A = +25^{\circ}$ C, Vss= -5V, Vdd= +5V, control Voltage = 0/ +5V, 50 Ohm System

Parameter	Min.	Тур.	Max.	Units
Frequency Range	3		6	GHz
Insertion Loss*		8	10.5	dB
Input Return Loss*		13		dB
Output Return Loss*		10		dB
Phase Error* 3.0 - 5.5 GHz   5.5 - 6.0 GHz		±5 -10	+15 / -25 +15 / -32	deg
RMS Phase Error		4		deg
Insertion Loss Variation*		±0.5		dB
Input Power for 1 dB Compression		31		dBm
Input Third Order Intercept		40		dBm
Control Voltage Current		35	250	μΑ
Bias Control Current		5	15	mA

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#### 0 -2 (qB) -4 **INSERTION LOSS** -6 -8 -10 -12 2 3 4 5 6 7 FREQUENCY (GHz)

Insertion Loss, Major States Only

Input Return Loss, Major States Only



**Output Return Loss, Major States Only** 



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Normalized Loss, Major States Only

# Phase Error, Major States Only



# Relative Phase Shift Major States Including All Bits



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### Relative Phase Shift, RMS, Average, Max, All States



# Input IP2, Major States Only



**RMS Phase Error vs. Temperature** 



# HMC649ALP6E

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## Input IP3, Major States Only



# Input P1dB, Major States Only



### Insertion Loss vs. Temperature, Major States Only



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# ROHS V

# HMC649ALP6E

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## Phase Error vs. State



# **Bias Voltage & Current**

Vdd	ldd
5.0	5.4mA
Vss	lss
-5.0	5.4mA

### **Control Voltage**

State	Bias Condition	
Low (0)	0 to 0.2 Vdc	
High (1)	Vdd ±0.2 Vdc @ 35 μΑ Typ.	

# Absolute Maximum Ratings

Input Power (RFIN)	32 dBm (T= +85 °C)	
Bias Voltage Range (Vdd)	-0.2 to +12V	
Bias Voltage Range (Vss)	+0.2 to -12V	
Channel Temperature (Tc)	150 °C	
Thermal Resistance (channel to ground paddle)	200 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class1A (Passed 250V)	



### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

# Truth Table

	Control Voltage Input					Phase Shift (Degrees)
Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	RFIN - RFOUT
0	0	0	0	0	0	Reference*
1	0	0	0	0	0	5.625
0	1	0	0	0	0	11.25
0	0	1	0	0	0	22.5
0	0	0	1	0	0	45.0
0	0	0	0	1	0	90.0
0	0	0	0	0	1	180.0
1	1	1	1	1	1	354.375
Any combina	Any combination of the above states will provide a phase shift approximately equal to the sum of the bits selected.					
*Reference c	*Reference corresponds to monotonic setting					

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# GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz





#### 6. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC649ALP6E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 <sup>[1]</sup>	H649A XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

# **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	Vdd	Voltage Supply	
2, 20	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
3	RFIN	This port is DC coupled and matched to 50 Ohms.	RFIN O
4 - 18, 21	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
19	RFOUT	This port is DC coupled and matched to 50 Ohms.	O RFOUT
22 - 24 26 - 28	BIT6, BIT5, BIT4, BIT3, BIT2, BIT1	Control Input. See truth table and control voltage tables.	
25	Vss	Voltage Supply	

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# HMC649ALP6E

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# **Evaluation PCB**



# List of Materials for Evaluation PCB EV1HMC649ALP5 [1][3]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3	Header 2mm, 16 pins	
C1, C2	1000pF, 0402 pkg	
U1	HMC649ALP6E 6-Bit Digital Phase Shifter	
PCB [2]	117718 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

[3] Please refer to part's pin description and functional diagram for pin out assignments on evaluation board.

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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